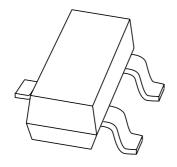
## **DISCRETE SEMICONDUCTORS**

# DATA SHEET



# **BAV23S**General purpose double diode

Product specification Supersedes data of 1999 May 05 2001 Oct 12





# General purpose double diode

#### BAV23S

#### **FEATURES**

- Small plastic SMD package
- Switching speed: max. 50 ns
- · General application
- Continuous reverse voltage: max. 200 V
- Repetitive peak reverse voltage: max. 250 V
- Repetitive peak forward current: max. 625 mA.

#### **APPLICATIONS**

· General purpose where high breakdown voltages are required.

#### **DESCRIPTION**

The BAV23S consists of two general purpose diodes connected in series fabricated in planar technology, and encapsulated in the small SOT23 plastic SMD package.

#### **MARKING**

TYPE NUMBER	MARKING CODE <sup>(1)</sup>
BAV23S	L31 or *V5

#### Note

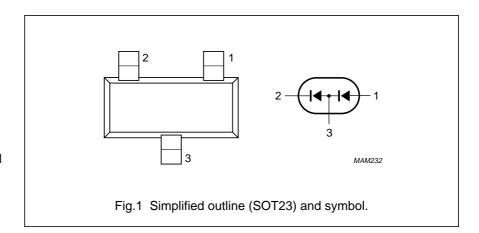
- 1. \* = p: Made in Hong Kong. \* = t: Made in Malaysia.
  - \* = W: Made in China.

#### PIN DESCRIPTION 1 anode 2 cathode

common connection

**PINNING** 

3



#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	PARAMETER CONDITIONS			
Per diode					
$V_{RRM}$	repetitive peak reverse voltage		_	250	V
$V_{RRM}$	repetitive peak reverse voltage	series connection	_	500	V
$V_R$	continuous reverse voltage		_	200	V
$V_R$	continuous reverse voltage	series connection	_	400	V
I <sub>F</sub>	continuous forward current	single diode loaded; note 1; see Fig.2	_	225	mA
		double diode loaded; note 1; see Fig.2	_	125	mA
I <sub>FRM</sub>	repetitive peak forward current		_	625	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; T <sub>j</sub> = 25 °C prior to surge; see Fig.4			
		t = 1 μs	_	9	Α
		t = 100 μs	_	3	Α
		t = 10 ms	_	1.7	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 1	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C

#### Note

1. Device mounted on an FR4 printed-circuit board.

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# General purpose double diode

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#### **ELECTRICAL CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	MAX.	UNIT	
Per diode				
V <sub>F</sub>	forward voltage	see Fig.3		
		I <sub>F</sub> = 100 mA	1.0	V
		I <sub>F</sub> = 200 mA	1.25	V
V <sub>F</sub>	forward voltage	series connection; see Fig.3		
		I <sub>F</sub> = 100 mA	2.0	V
		I <sub>F</sub> = 200 mA	2.5	V
I <sub>R</sub>	reverse current	see Fig.5		
		V <sub>R</sub> = 200 V	100	nA
		$V_R = 200 \text{ V}; T_j = 150 ^{\circ}\text{C}$	100	μΑ
I <sub>R</sub>	reverse current	series connection		
		V <sub>R</sub> = 400 V	100	nA
		$V_R = 400 \text{ V}; T_j = 150 ^{\circ}\text{C}$	100	μΑ
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0; see Fig.6	5	pF
t <sub>rr</sub>	reverse recovery time	when switched from $I_F$ = 30 mA to $I_R$ = 30 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 3 mA; see Fig.7	50	ns

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point		360	K/W
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	500	K/W

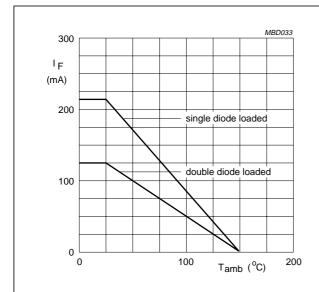
#### Note

1. Device mounted on an FR4 printed-circuit board.

# General purpose double diode

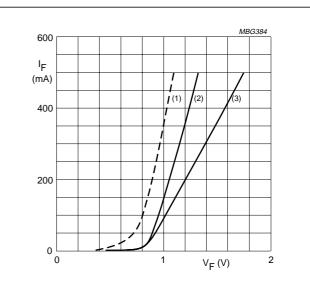
BAV23S

#### **GRAPHICAL DATA**



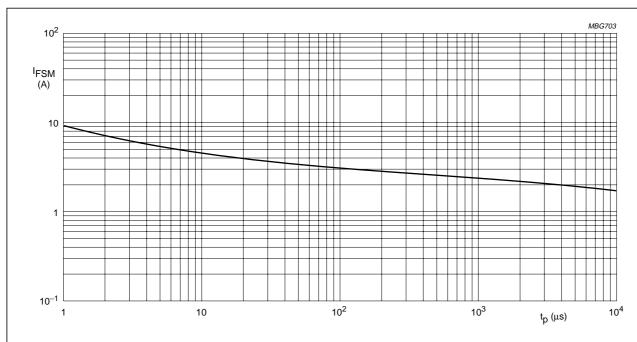
Device mounted on an FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (1)  $T_j = 150$  °C; typical values.
- (2)  $T_j = 25$  °C; typical values.
- (3)  $T_j = 25$  °C; maximum values.

Fig.3 Forward current as a function of forward voltage.

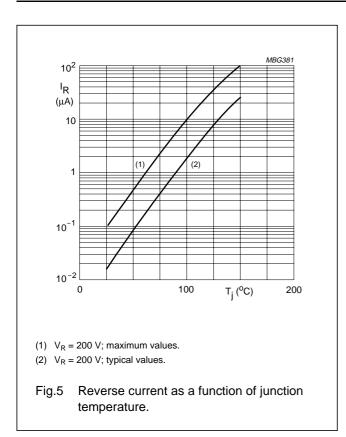


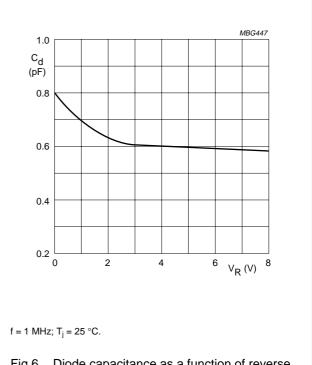
Based on square wave currents.  $T_j = 25$  °C prior to surge.

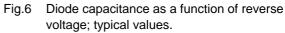
Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

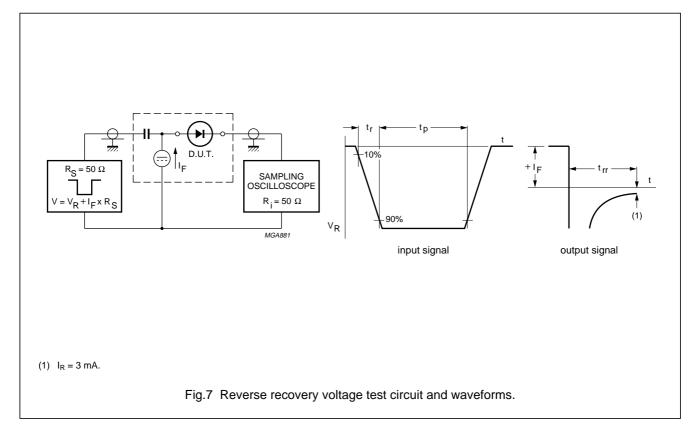
# General purpose double diode

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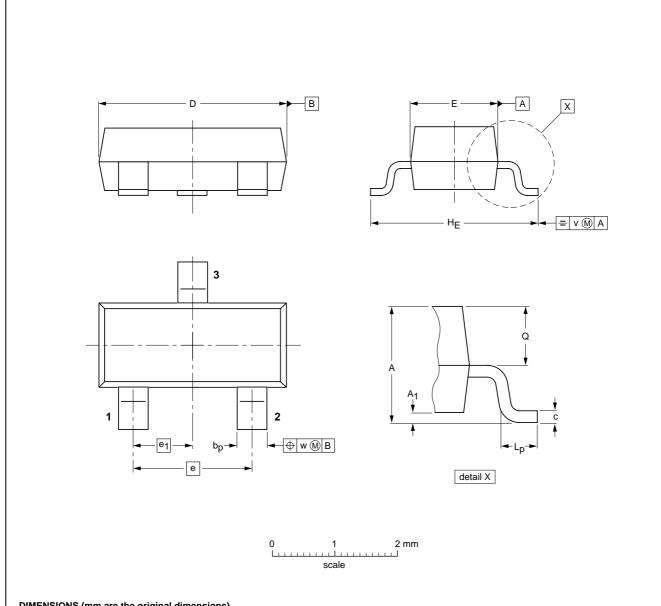
# General purpose double diode

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#### **PACKAGE OUTLINE**

Plastic surface mounted package; 3 leads

SOT23



<b>DIMENSIONS</b> (mm are	the original dimensions)
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UNIT	A	A <sub>1</sub> max.	bp	С	D	E	е	e <sub>1</sub>	HE	L <sub>p</sub>	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT23		TO-236AB				<del>-97-02-28-</del> 99-09-13

### General purpose double diode

BAV23S

#### **DATA SHEET STATUS**

DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
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